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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

421/P
OKON
PATENT APPLICATION
9/20/02

In Re U.S. Patent Application)
Applicant: Hongyong Zhang)
Serial No. 09/468,489)
Filed: December 20, 1999)
For: THIN FILM TRANSISTOR)
HAVING LIGHTLY AND)
HEAVILY DOPED SOURCE/)
DRAIN REGIONS AND ITS)
MANUFACTURE)
Art Unit: 2814)
Examiner: Quach, T.)

I hereby certify that this paper is being deposited with
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Patents, Washington, D.C. 20231, on this date.

August 28, 2002
Date

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AMENDMENT D

Assistant Commissioner for Patents
Washington, D.C. 20231

Dear Sir:

In response to the Office Action mailed March 28, 2002, please amend the
above-identified Application as follows:

IN THE SPECIFICATION:

Please replace the paragraph beginning on page 3, line 19, with the following
amended paragraph: